

## 温补振荡器 Temperature Compensated Crystal Oscillator: K(V)T14 K(V)T14S K(V)T14CS

### Feature 特征

- Available in CMOS, Clipped Sine, and True Sine Wave output 提供方波/正弦波/削峰正弦波输出类型
- Tight frequency stability  $\pm 1.0\text{ppm}$  over  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  宽温范围频率稳定性低
- VCTCXO option allows frequency tuning via control voltage 支持通过控制电压进行频率微调
- DIP 14 through-hole package for industrial applications 插件封装适合工业级应用
- Ideal for precision timing in communications, instrumentation, RF systems 满足通信, 仪器仪表, 射频系统中的精密时钟需求



### General Specifications 规格参考

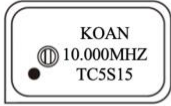
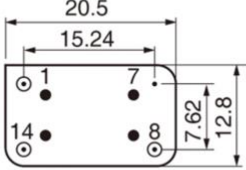
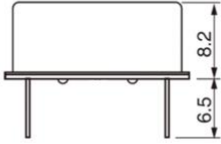
PARAMETER	性能参数	K(V)T14	K(V)T14S	K(V)T14CS		
Supply Voltage	工作电压	+3.3V; +5.0V; $\pm 12.0\text{V}$				
Frequency Range	频率范围	6.0~60.0MHz	10~200MHz	6.0~60.0MHz		
Standard Frequency	通用频率	10, 12.8, 16.384, 19.2, 20, 24.576, 25, 26, 30.72, 40, 50MHz				
Output Waveform	输出波形	CMOS	Sine	Clipped Sine		
Output Load	输出负载	15pF	50 $\Omega$	10K $\Omega$ /10pF $\pm 10\%$		
Output Logic	输出电平	High: $\geq 0.9V_{\text{dd}}$ Low: $\leq 0.1V_{\text{dd}}$	0.8Vp-p min.			
Initial Calibration Tolerance	调整频差	$\pm 0.5 \sim \pm 2.0\text{ppm}$				
Current Consumption	工作电流	40mA max	36mA max	40mA max		
EFC Linearity	非线性误差	正向 $\pm 10\%$ max.				
<b>Frequency Stability 频率稳定性 VS</b>						
Operating Temperature Range	温度范围	见下表				
Frequency Stability	温度频差					
Load Change	负载变化	$\pm 0.2\text{ppm}$ (Load $\pm 5\%$ )				
Voltage Change	电压变化	$\pm 0.2\text{ppm}$ ( $V_{\text{cc}}\pm 5\%$ )				
Aging	老化率	$\pm 1.0\text{ppm/year}$ max				
Frequency Tuning Method	频率调节方式	电压调节/机械微调/NC				
Control Voltage Range	控制电压范围	1.5 $\pm 1.0\text{V}$				
Frequency Tuning Range	频率调节范围	$\pm 5\text{ppm}$ min.				
Duty Cycle	占空比	45~55% ( $f \leq 40\text{MHz}$ ); 40~60% ( $f > 40\text{MHz}$ )	-	-		
Rise & Fall Time	上升下降时间	10ns max.	-	-		
Phase Noise @10MHz	相位噪声 Max (dBc/Hz)	-80	-115	-140	-145	-150
		10Hz	100Hz	1kHz	10kHz	100kHz
Input Impedance	输入电阻	1.0M $\Omega$ min.	-	-		
Modulation Bandwidth	调制宽带	3KHz min.				
Start-up Time	起振时间	5ms max.				
Storage Temperature Range	储存温度范围	$-55^\circ\text{C} \sim +125^\circ\text{C}$				

### Frequency Stability 温度频差 VS Operating Temperature Range 温度范围

Temp. Code	Temp. \ppm	$\pm 0.5$	$\pm 1.0$	$\pm 2.0$	$\pm 2.5$	$\pm 3.0$	$\pm 5.0$
A	$-10 \sim 60^\circ\text{C}$	○	○	○	○	○	○
B	$-20 \sim 70^\circ\text{C}$	○	○	○	○	○	○
C	$-40 \sim 85^\circ\text{C}$	○	○	○	○	○	○

NOTE: Please consult for other specifications 若有其它规格需求请告知

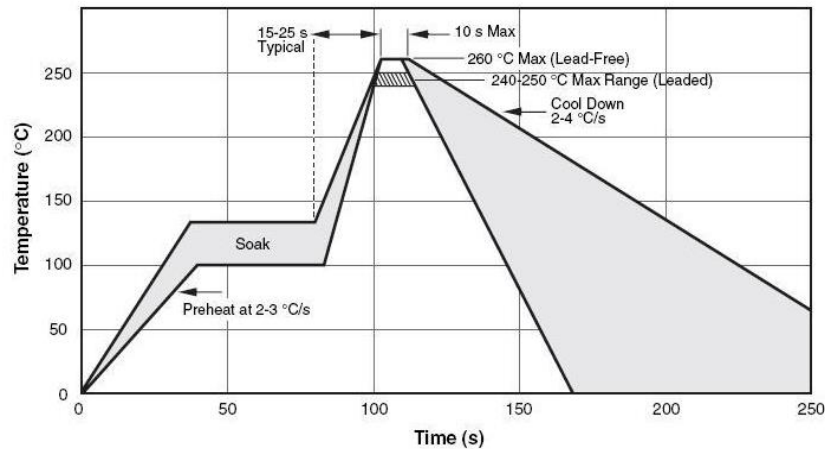
### ■ Outline Dimensions (Unit: mm) 外形尺寸

KT14 KT14S KT14CS				<table border="1"> <thead> <tr> <th>Pin</th> <th>Connection</th> </tr> </thead> <tbody> <tr> <td>#1</td> <td>GND or NC for TCXO Voltage Control for VCTCXO</td> </tr> <tr> <td>#7</td> <td>Ground</td> </tr> <tr> <td>#8</td> <td>Output</td> </tr> <tr> <td>#14</td> <td>Supply Voltage</td> </tr> </tbody> </table>	Pin	Connection	#1	GND or NC for TCXO Voltage Control for VCTCXO	#7	Ground	#8	Output	#14	Supply Voltage
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#7	Ground													
#8	Output													
#14	Supply Voltage													

### ■ Part Number Guide 产品编号

<u>K(V)T14CS</u>	-	<u>20.000</u>	-	<u>33</u>	-	<u>C</u>	-	<u>03</u>	-	<u>NS</u>
↓		↓		↓		↓		↓		↓
型号		标称频率		工作电压		工作温度		温度频差		特殊要求
‘KT’:温补系列 KT: TCXO KVT: VCTCXO ‘14’:封装尺寸 DIP-14 ‘CS’: 输出波形 Clipped Sine		(In MHz)		33=3.3V 50=5.0V 12=12V		A: -10~+60°C B: -20~+70°C C: -40~+85°C		A5 = ±0.5ppm 01 = ±1.0ppm 02 = ±2.0ppm 025 = ±2.5ppm 03 = ±3.0ppm 05 = ±5.0ppm		‘NS’:特殊要求

### ■ Wave Solder Profile 波峰焊



Average Ramp-up Rate	升温速度	~200°C/Second
Heating Rate during preheat	预热速度	1~2°C/second typ.; 4°C/second max
Final Preheat Temperature Ts	最终预热温度	~130°C
Peak Temperature Tp	最高温度	260°C
Time within +0°C/-5°C of actual temperature tp	实际温度时间	10 seconds
Ramp-Down Rate	降温速度	5°C/second max